

Product specification

1990 Feb 09

IC15 Data Handbook



PHILIPS

74F3037

FEATURES

- 30Ω line driver
- 67mA output drive capability in the high state
- High speed
- · Facilitates incident wave switching
- 3nh lead inductance each on V_{CC} and GND when both side pins are used
- 160mA output drive capability in the low state
- Industrial temperature range available (-40°C to +85°C)

DESCRIPTION

The 74F3037 is a high current line driver composed of four 2–input NAND gates. It has been designed to deal with the

ORDERING INFORMATION

transmission line effects of PC boards which appear when fast edge rates are used.

The drive capability of the 74F3037 is 67mA source and 160mA sink with a V_{CC} as low as 4.5V. This guarantees incident wave switching with V_{OH} not less than 2.0V and V_{OL} not more than 0.8mA while driving impedances as low as 30 ohms. This is applicable with any combination of outputs using continuous duty. The propagation delay of the part is minimally affected by reflections when terminated only by the TTL inputs of other devices. Performances may be improved by full or partial line termination.

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT(TOTAL)
74F3037	2.0ns	16mA

		DRDER CODE	
DESCRIPTION	COMMERCIAL RANGE V_{CC} = 5V ±10%, T_{amb} = 0°C to +70°C	INDUSTRIAL RANGE V_{CC} = 5V \pm 10%, T_{amb} = -40°C to +85°C	PKG DWG #
16-pin plastic DIP	N74F3037N	I74F3037N	SOT38-4
16-pin plastic SOL	N74F3037D	I74F3037D	SOT162-1

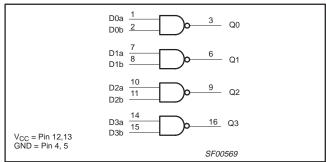
INPUT AND OUTPUT LOADING AND FAN OUT TABLE

PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
Dna, Dnb	Data inputs	1.0/1.0	20µA/0.6mA
Qn	Data output	3350/266	67mA/160mA

Note to input and output loading and fan out table

One (1.0) FAST unit load is defined as: 20µA in the high state and 0.6mA in the low state.

LOGIC DIAGRAM



FUNCTION TABLE

INP	UTS	OUTPUT
Dna	Dnb	Qn
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

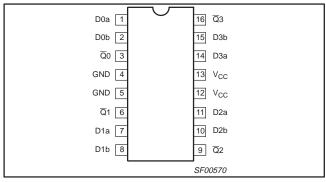
Notes to function table

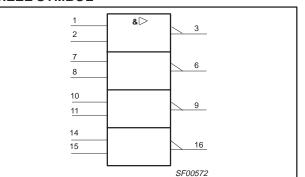
H = High voltage level

L = Low voltage level

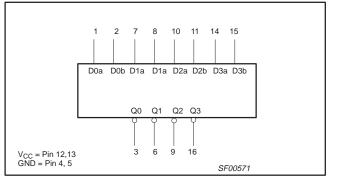
74F3037

PIN CONFIGURATION





LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V _{CC}	Supply voltage		-0.5 to +7.0	V
V _{IN}	Input voltage		-0.5 to +7.0	V
I _{IN}	Input current		-30 to +5	mA
V _{OUT}	Voltage applied to output in high output state		–0.5 to V_{CC}	V
I _{OUT}	Current applied to output in low output state		320	mA
T _{amb}	Operating free air temperature range	Commercial range	0 to +70	°C
		Industrial range	-40 to +85	°C
T _{stg}	Storage temperature range		-65 to +150	°C

IEC/IEEE SYMBOL

74F3037

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER			LIMITS		T _A =	
UNIT			MIN	NOM	MAX	-40 to +85°C	
V _{CC}	Supply voltage		4.5	5.0	5.5	V	
V _{IH}	High-level input voltage		2.4			V	
V _{IL}	Low-level input voltage				0.8	V	
I _{lk}	Input clamp current				-18	mA	
I _{OH}	High–level output current				-67	mA	
I _{OL}	Low-level output current				160	mA	
T _{amb}	Operating free air temperature range	Commercial range	0		+70	°C	
		Industrial range	-40		+85	°C	

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER		٦	TEST			LIMITS		UNIT
		CON	DITIONS ¹		MIN	TYP ²	MAX		
			V _{CC} = MIN,	I _{OH} = -45mA	±10%V _{CC}	2.5			V
V _{OH}	High-level output voltage		$V_{IL} = MAX,$		±5%V _{CC}	2.7			V
			$V_{IH} = MIN$	I _{OH1} = 67mA ³	±10%V _{CC}	2.0			V
V _{OL}	Low-level output voltage		$V_{CC} = MIN, V_{IL} = MAX,$	I _{OL} = 100mA	±10%V _{CC}		0.30	0.50	V
			$V_{IH} = MIN$	I _{OL1} = 160mA ⁴	±5%V _{CC}		0.30	0.50	V
V _{IK}	Input clamp voltage		$V_{CC} = MIN, I_I = I_{IK}$				-0.73	-1.2	V
lı	Input current at maximum input vol	tage	$V_{CC} = MAX, V_I = 7.0V$					100	μΑ
IIH	High–level input current	High–level input current		$V_{CC} = MAX, V_I = 2.7V$				20	μΑ
IIL	Low-level input current		$V_{CC} = MAX, V_I = 0.5V$					-0.6	mA
lo	Output current ⁵		$V_{CC} = MAX, V_{O} = 2.25V$	1		-100		-200	mA
I _{CC}	Supply current (total) I _{CCH}		V _{CC} = MAX				6.0	9.0	mA
		I _{CCL}]				30	40	mA

Notes to DC electrical characteristics

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

2. All typical values are at $V_{CC} = 5V$, $T_{amb} = 25^{\circ}C$.

3. I_{OH1} is the current necessary to guarantee the low to high transition in a 30 ohm transmission line on the incident wave. 4. I_{OL1} is the current necessary to guarantee the high to low transition in a 30 ohm transmission line on the incident wave.

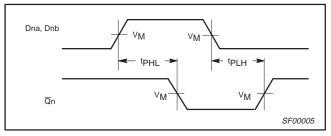
5. Io is tested under conditions that produce current approximately one half of the true short-circuit current (Ios).

AC ELECTRICAL CHARACTERISTICS

						LI	MITS			
			Tar	_{nb} = +25	i° C	$T_{amb} = 0^{\circ}C$	C to +70°C	$T_{amb} = -40^{\circ}$	C to +85°C	1
SYMBOL	PARAMETER	TEST		_C = +5.0			0V \pm 10%	V _{CC} = +5.		
		CONDITION		L = 50pl		C _L = \$		C _L = 5		
			ĸ	L = 5009	.2	R _L = 5	50022	R _L = \$	50022	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dna, Dnb to Qn	Waveform 1	1.0 1.0	2.0 2.0	5.0 4.5	1.0 1.0	5.5 5.0	1.0 1.0	5.5 5.0	ns

74F3037

AC WAVEFORMS

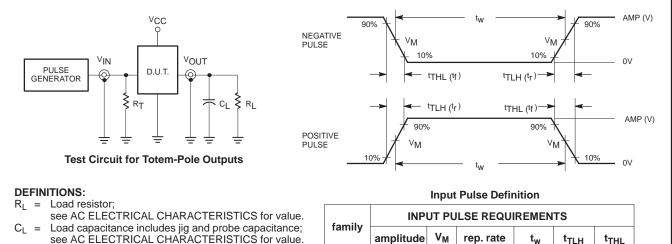


Waveform 1. Propagation delay for inverting outputs

Note to AC waveforms

For all waveforms, $V_{\mbox{\scriptsize M}}$ = 1.5V.

TEST CIRCUIT AND WAVEFORMS



74F

3.0V

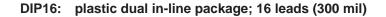
1.5V

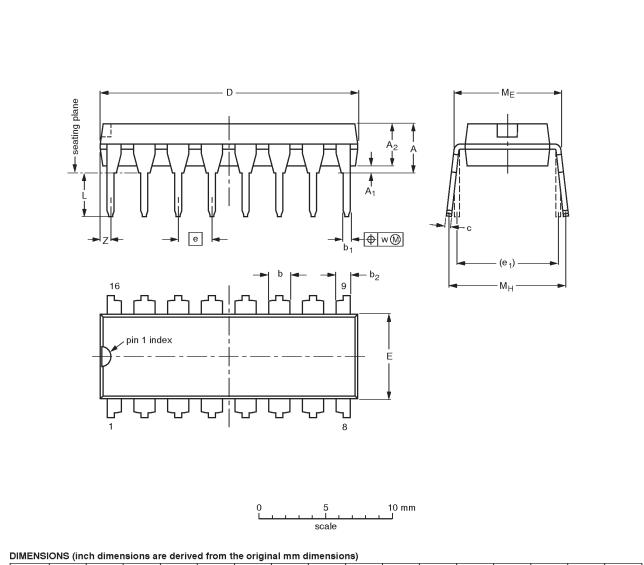
1MHz

see AC ELECTRICAL CHARACTERISTICS for value. R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SF00006

500ns 2.5ns 2.5ns





UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	c	D ⁽¹⁾	Е ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

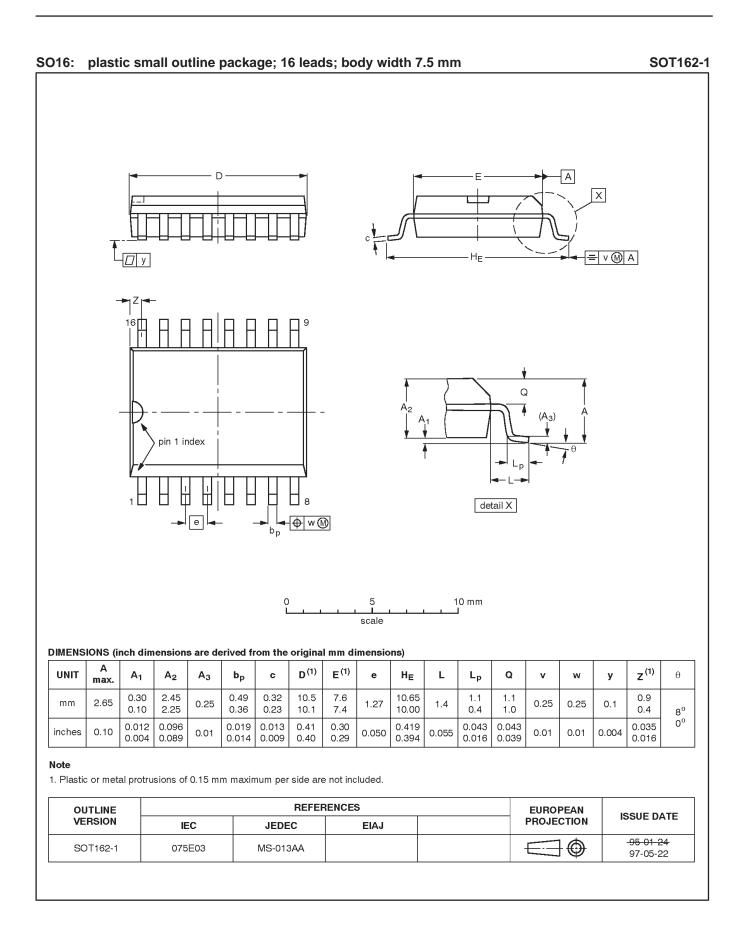
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT38-4					-92-11-17 95-01-14

Product specification

74F3037

SOT38-4

74F3037



Quad 2-input NAND 30Ω driver

74F3037

Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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